

Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 200 V

Forward Current - 3 A

FEATURES

- ◆Metal silicon junction, majority carrier conduction
- ◆For surface mounted applications
- ◆Low power loss, high efficiency
- ◆High forward surge current capability
- ◆For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆Lead free in comply with EU RoHS 2011/65/EU directives

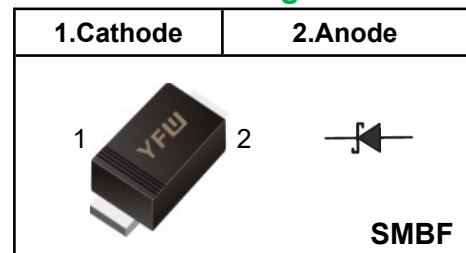
MECHANICAL DATA

- ◆Case: SMBF
- ◆Terminals: Solderable per MIL-STD-750, Method 2026
- ◆Approx. Weight: 57mg / 0.002oz

Absolute Maximum Ratings and Electrical characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Pinning



Marking Code

SS32BF	YFW S32B
SS34BF	YFW S34B
SS36BF	YFW S36B
SS38BF	YFW S38B
SS310BF	YFW S310B
SS312BF	YFW S312B
SS315BF	YFW S315B
SS320BF	YFW S320B

Parameter	Symbols	SS32BF	SS34BF	SS36BF	SS38BF	SS310BF	SS312BF	SS315BF	SS320BF	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	40	60	80	100	120	150	200	V
Maximum RMS voltage	V_{RMS}	14	28	42	56	70	84	105	140	V
Maximum DC Blocking Voltage	V_{DC}	20	40	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current	I_{F(AV)}	3.0								A
Peak Forward Surge Current,8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	80								A
Peak Forward Surge Current,1.0ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	160								A
I ² t Rating for fusing(3ms≤t≤8.3ms)	I²t	26.5								A
Maximum Instantaneous Forward Voltage at 3 A	V_F	0.55		0.70	0.85		0.95			V
Maximum Instantaneous Reverse Current T _A = 25°C at Rated DC Reverse Voltage T _A = 100°C	I_R	0.5 5			0.3 3					mA
Typical Junction Capacitance ⁽¹⁾	C_j	135		107	83		68		50	pF
Typical Thermal Resistance ⁽²⁾	R_{θJA} R_{θJC} R_{θJL}	100 20 25								°C/W
Operating Junction Temperature Range	T_J	-55 ~ +150								°C
Storage Temperature Range	T_{stg}	-55 ~ +150								°C

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

Fig.1 Forward Current Derating Curve

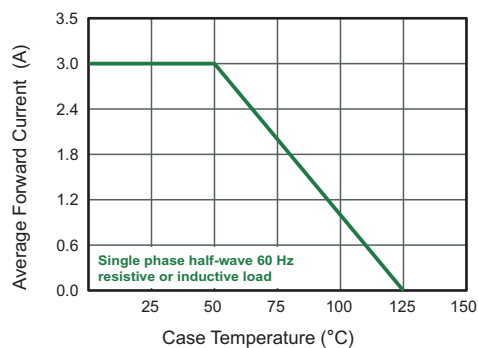


Fig.2 Typical Reverse Characteristics

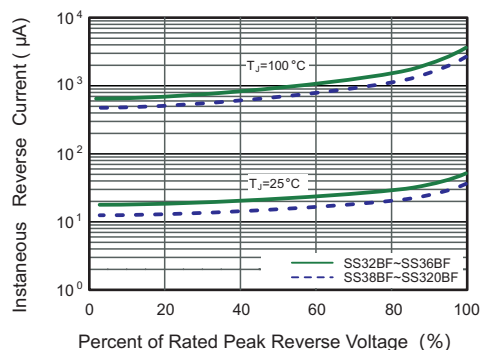


Fig.3 Typical Forward Characteristic

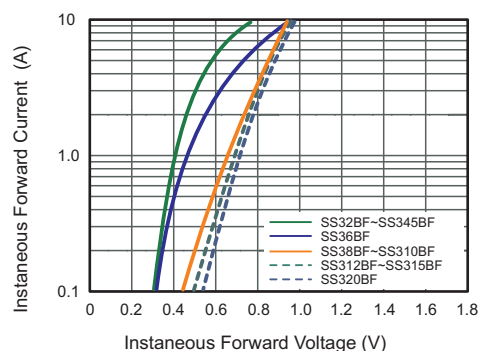


Fig.4 Typical Junction Capacitance

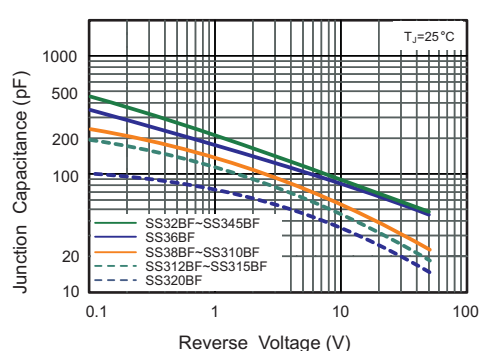
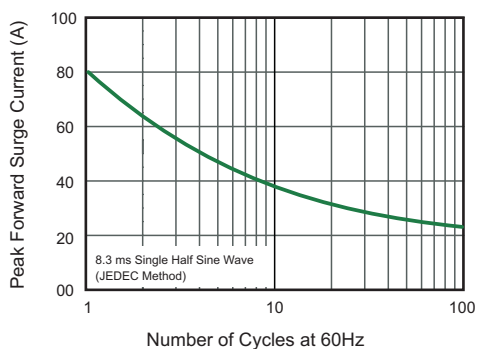
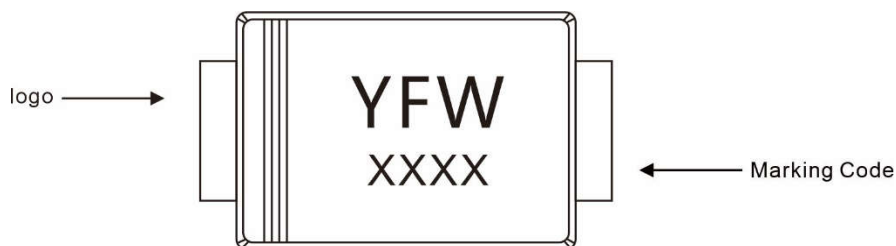


Fig.5 Maximum Non-Repetitive Forward Surge Current



Marking Diagram



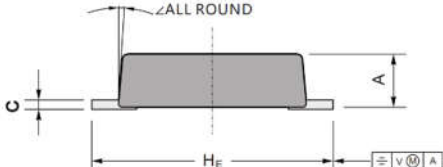
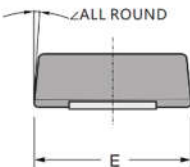
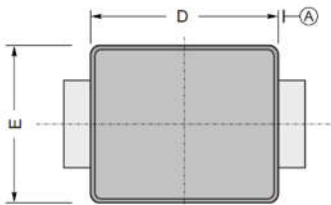
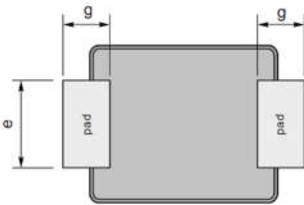
Ordering information

Package	Packing Description	Packing Quantity
SMBF	Tape/Reel, 13" reel	5000PCS/Reel 50000PCS/Carton

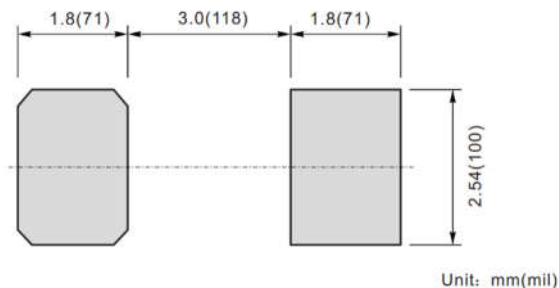
Package Dimensions

SMBF

Dim.	Millimeter(mm)		mil	
	Min.	Max.	Min.	Max.
A	1.1	1.3	43	51
C	0.18	0.26	7	10
D	4.2	4.4	165	173
E	3.5	3.7	138	146
H _E	5.1	5.5	200	216
e	2.2	1.9	75	86
g	1.0		40	
∠	9°			

	
	
Top View	Bottom View

The recommended mounting pad size



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